

3.3V CMOS Static RAM 4 Meg (256K x 16-Bit)

Features

- 256K x 16 advanced high-speed CMOS Static RAM
- JEDEC Center Power / GND pinout for reduced noise.
- Equal access and cycle times
 - Commercial and Industrial: 10/12/15ns
- One Chip Select plus one Output Enable pin
- Bidirectional data inputs and outputs directly LVTTL-compatible
- Low power consumption via chip deselect
- Upper and Lower Byte Enable Pins
- Single 3.3V power supply
- Available in 44-pin, 400 mil plastic SOJ package and a 44pin, 400 mil TSOP Type II package and a 48 ball grid array, 9mm x 9mm package.
- Green parts available, see ordering information

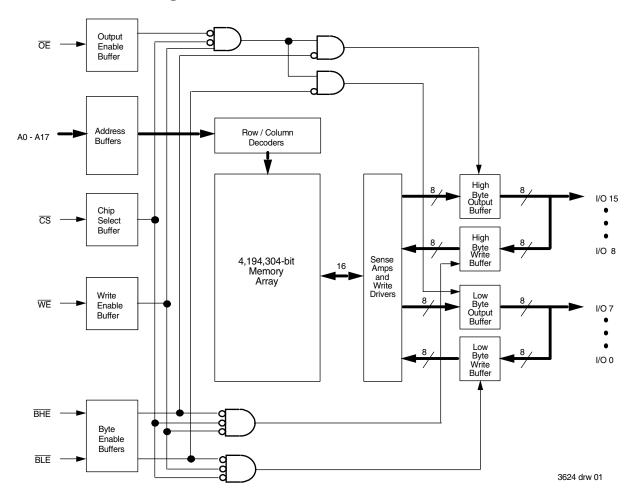
Description

The IDT71V416 is a 4,194,304-bit high-speed Static RAM organized as 256K x 16. It is fabricated using high-performance, high-reliability CMOS technology. This state-of-the-art technology, combined with innovative circuit design techniques, provides a cost-effective solution for high-speed memory needs.

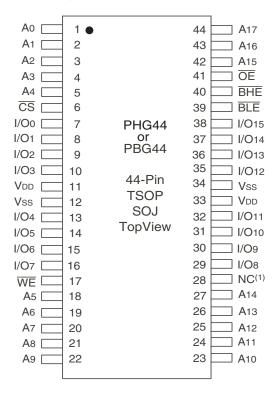
The IDT71V416 has an output enable pin which operates as fast as 5ns, with address access times as fast as 10ns. All bidirectional inputs and outputs of the IDT71V416 are LVTTL-compatible and operation is from a single 3.3V supply. Fully static asynchronous circuitry is used, requiring no clocks or refresh for operation.

The IDT71V416 is packaged in a 44-pin, 400 mil Plastic SOJ and a 44-pin, 400 mil TSOP Type II package and a 48 ball grid array, 9mm x 9mmpackage.

Functional Block Diagram



Pin Configurations - SOJ/TSOP(2)



3624 drw 02

NOTES:

- 1. Pin 28 can either be a NC or connected to Vss.
- 2. This text does not indicate orientation of actual part-marking.

Pin Descriptions

A0 - A17	Address Inputs	Input
CS	Chip Select	Input
WE	Write Enable	Input
ŌĒ	Output Enable	Input
BHE	High Byte Enable	Input
BLE	Low Byte Enable	Input
I/Oo - I/O15	Data Input/Output	I/O
VDD	3.3V Power	Pwr
Vss	Ground	Gnd

3624 tbl 01

Pin Configurations - BGA⁽¹⁾

BE48, BEG48

	1	2	3	4	5	6
Α	BLE	ŌĒ	A ₀	A 1	A2	NC
В	I/O ₀	BHE	A 3	A4	cs	I/O8
С	I/O ₁	I/O ₂	A 5	A6	V O10	I/O9
D	Vss	I/O3	A 17	A 7	I /O11	Vdd
Ε	VDD	1/04	NC	A 16	V O12	Vss
F	1/06	I/O ₅	A 14	A 15	V O13	I/O14
G	1/07	NC	A 12	A 13	WE	I/O15
Н	NC	A8	А9	A 10	A 11	NC
						3624 tbl 11

Top View

NOTE:

1. This text does not indicate orientation of actual part-marking.

SOJ Capacitance

 $(TA = +25^{\circ}C, f = 1.0MHz)$

Symbol	Parameter ⁽¹⁾	Conditions	Max.	Unit
Cin	Input Capacitance	VIN = 3dV	7	pF
Ci/o	I/O Capacitance	Vout = 3dV	8	pF

3624 tbl 02

BGA Capacitance

 $(TA = +25^{\circ}C, f = 1.0MHz)$

Symbol	Parameter ⁽¹⁾	Conditions	Max.	Unit
CIN	Input Capacitance	VIN = 3dV	6	pF
Cvo	I/O Capacitance	Vout = 3dV	7	pF

NOTE:

tested.

1. This parameter is guaranteed by device characterization, but not production

Absolute Maximum Ratings(1)

Symbol	Rating	Value	Unit
VDD	Supply Voltage Relative to Vss	-0.5 to +4.6	V
VIN, VOUT Terminal Voltage Relative to Vss		-0.5 to VDD+0.5	V
TBIAS	Temperature Under Bias	-55 to +125	°C
Tstg	Storage Temperature	-55 to +125	°C
Рт	Power Dissipation	1	W
Іоит	DC Output Current	50	mA

3624 tbl 04

NOTE:

 Stresses greater than those listed under ABSOLUTE MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

Recommended Operating Temperature and Supply Voltage

Grade Temperature		Vss	V DD
Commercial	0°C to +70°C	0V	See Below
Industrial	-40°C to +85°C	0V	See Below

3624 tbl 05

Recommended DC Operating Conditions

Symbol	Parameter	Min.	Тур.	Max.	Unit
VDD	Supply Voltage	3.0	3.3	3.6	V
Vss	Ground	0	0	0	V
ViH	Input High Voltage	2.0		VDD+0.3 ⁽¹⁾	V
VIL	Input Low Voltage	-0.3 ⁽²⁾		0.8	٧

NOTES:

- 3024 IDI U
- 1. VIH (max.) = VDD+2V for pulse width less than 5ns, once per cycle.
- 2. VIL (min.) = -2V for pulse width less than 5ns, once per cycle.

Truth Table⁽¹⁾

<u>cs</u>	ŌĒ	WE	BLE	BHE	I/O ₀ -I/O ₇	I/O8-I/O15	Function
Н	Х	Х	Х	Х	High-Z	High-Z	Deselected - Standby
L	L	Н	L	Н	DATAout	High-Z	Low Byte Read
L	L	Н	Н	L	High-Z	DATAout	High Byte Read
L	L	Н	L	L	DATAout	DATAout	Word Read
L	Х	L	L	L	DATAIN	DATAIN	Word Write
L	Х	L	L	Н	DATAIN	High-Z	Low Byte Write
L	Х	L	Н	L	High-Z	DATAIN	High Byte Write
L	Н	Н	Х	Х	High-Z	High-Z	Outputs Disabled
L	Х	Х	Н	Н	High-Z	High-Z	Outputs Disabled

NOTE:

1. $H = V_{IH}$, $L = V_{IL}$, X = Don't care.

3624 tbl 03

DC Electrical Characteristics

(VDD = Min. to Max., Commercial and Industrial Temperature Ranges)

			IDT71V416		
Symbol	Parameter	Test Conditions	Min.	Max.	Unit
Iu	Input Leakage Current	Vcc = Max., Vin = Vss to Vdd		5	μΑ
ILO	Output Leakage Current	VDD = Max., $\overline{\text{CS}}$ = ViH, VOUT = Vss to VDD		5	μΑ
Vol	Output Low Voltage	IOL = 8mA, VDD = Min.	-	0.4	٧
Vон	Output High Voltage	Iон = -4mA, V _{DD} = Min.	2.4		٧

3624 tbl 07

3624 tbl 08

DC Electrical Characteristics(1, 2, 3)

(VDD = Min. to Max., VLC = 0.2V, VHC = VDD - 0.2V)

			71V416S/L10		71V416S/L12		71V416S/L15		
Symbol	Parameter		Com'l.	Ind.	Com'l.	Ind.	Com'l.	Ind.	Unit
lcc	Dynamic Operating Current	S	200	200	180	180	170	170	mA
	$\overline{CS} \leq VLC$, Outputs Open, VDD = Max., f = fmax ⁽⁴⁾		180	180	170	170	160	160	
ISB	Dynamic Standby Power Supply Current $\overline{CS} \ge VHC$, Outputs Open, $VDD = Max.$, $f = fMax^{(4)}$		70	70	60	60	50	50	mA
			50	50	45	45	40	40	
ISB1			20	20	20	20	20	20	mA
	$\overline{\text{CS}} \ge \text{VHC}$, Outputs Open, $\text{Vdd} = \text{Max.}$, $f = 0^{(4)}$	L	10	10	10	10	10	10	

NOTES:

- 1. All values are maximum guaranteed values.
- 2. All inputs switch between 0.2V (Low) and VDD -0.2V (High).
- 3. Power specifications are preliminary.
- 4. fMAX = 1/trc (all address inputs are cycling at fmax); f = 0 means no address input lines are changing.

AC Test Loads

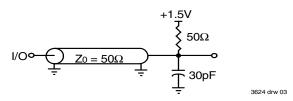


Figure 1. AC Test Load

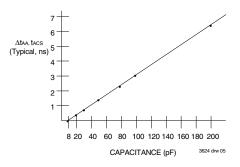
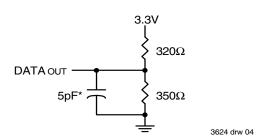


Figure 3. Output Capacitive Derating



*Including jig and scope capacitance.

Figure 2. AC Test Load (for tclz, tolz, tchz, tohz, tow, and twhz)

AC Test Conditions

	1
Input Pulse Levels	GND to 3.0V
Input Rise/Fall Times	1.5ns
Input Timing Reference Levels	1.5V
Output Reference Levels	1.5V
AC Test Load	Figures 1,2 and 3

3624 tbl 09

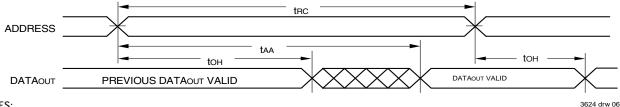
AC Electrical Characteristics

(VDD = Min. to Max., Commercial and Industrial Temperature Ranges)

		71V41	6S/L10	71V41	6S/L12	71V41	6S/L15	
Symbol	Parameter	Min.	Max.	Min.	Max.	Min.	Max.	Unit
READ CYCLI	E	•						
trc	Read Cycle Time	10	_	12		15	_	ns
taa	Address Access Time		10	_	12		15	ns
tacs	Chip Select Access Time		10	_	12		15	ns
tcLz ⁽¹⁾	Chip Select Low to Output in Low-Z	4	_	4	_	4	_	ns
tснz ⁽¹⁾	Chip Select High to Output in High-Z	_	5	_	6		7	ns
toe	Output Enable Low to Output Valid		5	_	6		7	ns
toLz ⁽¹⁾	Output Enable Low to Output in Low-Z	0	_	0		0	_	ns
tонz ⁽¹⁾	Output Enable High to Output in High-Z	_	5	_	6		7	ns
toн	Output Hold from Address Change	4	_	4		4	_	ns
tBE	Byte Enable Low to Output Valid	_	5	_	6		7	ns
tBLZ ⁽¹⁾	Byte Enable Low to Output in Low-Z	0	_	0		0		ns
tвнz ⁽¹⁾	Byte Enable High to Output in High-Z	_	5	_	6		7	ns
WRITE CYCL	E							
twc	Write Cycle Time	10	_	12	_	15	_	ns
taw	Address Valid to End of Write	8	_	8		10		ns
tcw	Chip Select Low to End of Write	8	_	8	_	10		ns
tвw	Byte Enable Low to End of Write	8	_	8		10		ns
tas	Address Set-up Time	0	_	0		0		ns
twr	Address Hold from End of Write	0	_	0		0		ns
twp	Write Pulse Width	8	_	8	_	10	_	ns
tow	Data Valid to End of Write	5		6		7		ns
tон	Data Hold Time	0		0		0		ns
tow ⁽¹⁾	Write Enable High to Output in Low-Z	3		3	_	3		ns
twHZ ⁽¹⁾	Write Enable Low to Output in High-Z		6		7		7	ns

3624 tbl 10

Timing Waveform of Read Cycle No. 1(1,2,3)

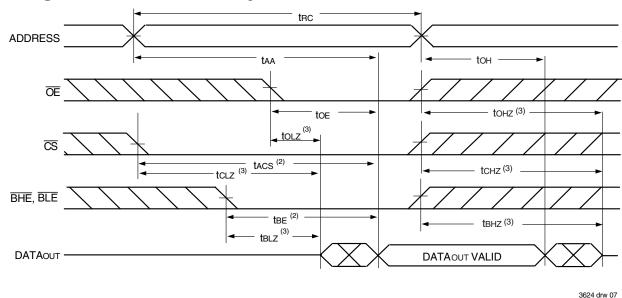


NOTES:

- WE is HIGH for Read Cycle.
 Device is continuously selected, \$\overline{CS}\$ is LOW.
- 3. $\overline{\text{OE}}$, $\overline{\text{BHE}}$, and $\overline{\text{BLE}}$ are LOW.

^{1.} This parameter is guaranteed with the AC Load (Figure 2) by device characterization, but is not production tested.

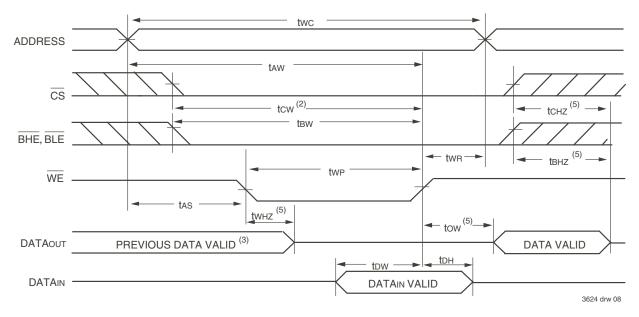
Timing Waveform of Read Cycle No. 2⁽¹⁾



NOTES:

- 1. WE is HIGH for Read Cycle.
- 2. Address must be valid prior to or coincident with the later of $\overline{\text{CS}}$, $\overline{\text{BHE}}$, or $\overline{\text{BLE}}$ transition LOW; otherwise tax is the limiting parameter.
- 3. Transition is measured ±200mV from steady state.

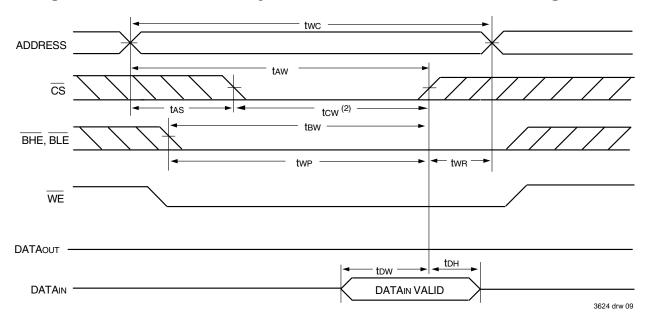
Timing Waveform of Write Cycle No. 1 (WE Controlled Timing)(1,2,4)



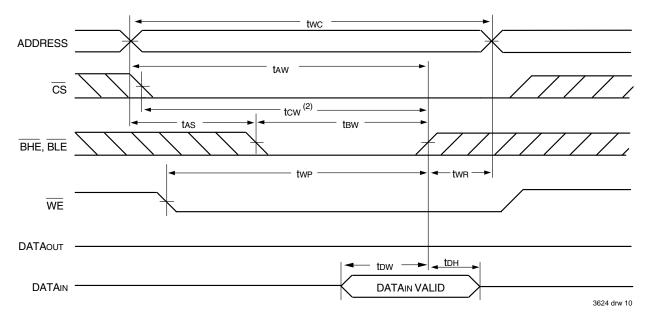
NOTES:

- 1. A write occurs during the overlap of a LOW $\overline{\text{CS}}$, LOW $\overline{\text{BHE}}$ or $\overline{\text{BLE}}$, and a LOW $\overline{\text{WE}}$.
- 2. $\overline{\text{OE}}$ is continuously HIGH. If during a $\overline{\text{WE}}$ controlled write cycle $\overline{\text{OE}}$ is LOW, twp must be greater than or equal to twHz + tbw to allow the I/O drivers to turn off and data to be placed on the bus for the required tbw. If $\overline{\text{OE}}$ is HIGH during a $\overline{\text{WE}}$ controlled write cycle, this requirement does not apply and the minimum write pulse is as short as the specified twp.
- 3. During this period, I/O pins are in the output state, and input signals must not be applied.
- 4. If the CS LOW or BHE and BLE LOW transition occurs simultaneously with or after the WE LOW transition, the outputs remain in a high-impedance state.
- 5. Transition is measured ±200mV from steady state.

Timing Waveform of Write Cycle No. 2 (CS Controlled Timing)(1,3)

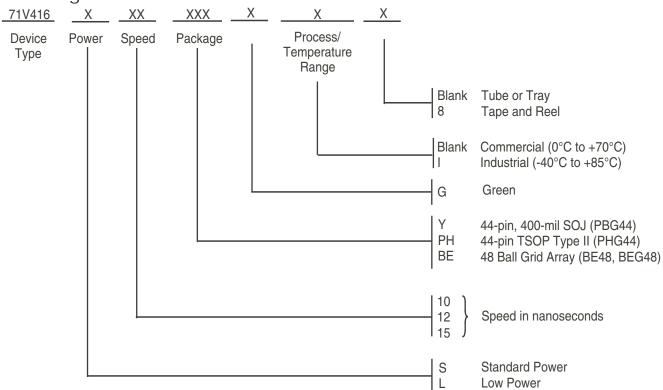


Timing Waveform of Write Cycle No. 3 (**BHE**, **BLE** Controlled Timing)^(1,3)



- 1. A write occurs during the overlap of a LOW $\overline{\text{CS}}$, LOW $\overline{\text{BHE}}$ or $\overline{\text{BLE}}$, and a LOW $\overline{\text{WE}}$.
- During this period, I/O pins are in the output state, and input signals must not be applied.
 If the CS LOW or BHE and BLE LOW transition occurs simultaneously with or after the WE LOW transition, the outputs remain in a high-impedance state.

Ordering Information



Orderable Part Information

Speed (ns)	Orderable Part ID	Pkg. Code	Pkg. Type	Temp. Grade
10	71V416L10BE	BE48	CABGA	С
	71V416L10BEG	BEG48	CABGA	С
	71V416L10BEG8	BEG48	CABGA	С
	71V416L10PHG	PHG44	TSOP	С
	71V416L10PHG8	PHG44	TSOP	С
	71V416L10PHGI	PHG44	TSOP	I
	71V416L10PHGI8	PHG44	TSOP	ı
	71V416L10YG	PBG44	SOJ	С
	71V416L10YG8	PBG44	SOJ	С
12	71V416L12BE	BE48	CABGA	С
	71V416L12BE8	BE48	CABGA	С
	71V416L12BEG	BEG48	CABGA	С
	71V416L12BEG8	BEG48	CABGA	С
	71V416L12BEGI	BEG48	CABGA	ı
	71V416L12BEGI8	BEG48	CABGA	ı
	71V416L12BEI	BE48	CABGA	ı
	71V416L12BEI8	BE48	CABGA	ı
	71V416L12PHG	PHG44	TSOP	С
	71V416L12PHG8	PHG44	TSOP	С
	71V416L12PHGI	PHG44	TSOP	_
	71V416L12PHGI8	PHG44	TSOP	I
	71V416L12YG	PBG44	SOJ	С
	71V416L12YG8	PBG44	SOJ	С
	71V416L12YGI	PBG44	SOJ	I
	71V416L12YGI8	PBG44	SOJ	I

3624 drw 11a

Speed (ns)	Orderable Part ID	Pkg. Code	Pkg. Type	Temp. Grade
10	71V416S10BE	BE48	CABGA	С
	71V416S10BE8	BE48	CABGA	С
	71V416S10BEG	BEG48	CABGA	С
	71V416S10BEG8	BEG48	CABGA	С
	71V416S10PHG	PHG44	TSOP	С
	71V416S10PHG8	PHG44	TSOP	С
	71V416S10PHGI	PHG44	TSOP	I
	71V416S10PHGI8	PHG44	TSOP	I
	71V416S10YG	PBG44	SOJ	С
	71V416S10YG8	PBG44	SOJ	С
12	71V416S12BE	BE48	CABGA	С
	71V416S12BE8	BE48	CABGA	С
	71V416S12BEG	BEG48	CABGA	С
	71V416S12BEG8	BEG48	CABGA	С
	71V416S12BEI	BE48	CABGA	l
	71V416S12BEI8	BE48	CABGA	Ì
	71V416S12PHG	PHG44	TSOP	С
	71V416S12PHG8	PHG44	TSOP	С
	71V416S12PHGI	PHG44	TSOP	I
	71V416S12PHGI8	PHG44	TSOP	I
	71V416S12YG	PBG44	SOJ	С
	71V416S12YG8	PBG44	SOJ	С
	71V416S12YGI	PBG44	SOJ	I
	71V416S12YGI8	PBG44	SOJ	ı

3624 tbl 12a

Orderable Part Information (con't)

Speed (ns)	Orderable Part ID	Pkg. Code	Pkg. Type	Temp. Grade
15	71V416L15BE	BE48	CABGA	С
	71V416L15BE8	BE48	CABGA	С
	71V416L15BEG	BEG48	CABGA	С
	71V416L15BEG8	BEG48	CABGA	С
	71V416L15BEGI	BEG48	CABGA	I
	71V416L15BEGI8	BEG48	CABGA	1
	71V416L15BEI	BE48	CABGA	I
	71V416L15BEI8	BE48	CABGA	ı
	71V416L15PHG	PHG44	TSOP	С
	71V416L15PHG8	PHG44	TSOP	С
	71V416L15PHGI	PHG44	TSOP	I
	71V416L15PHGI8	PHG44	TSOP	ı
	71V416L15YGI	PBG44	SOJ	ı
	71V416L15YGI8	PBG44	SOJ	1

Speed (ns)	Orderable Part ID	Pkg. Code	Pkg. Type	Temp. Grade
15	71V416S15BE	BE48	CABGA	С
	71V416S15BE8	BE48	CABGA	С
	71V416S15BEG	BEG48	CABGA	С
	71V416S15BEG8	BEG48	CABGA	С
	71V416S15BEGI	BEG48	CABGA	I
	71V416S15BEGI8	BEG48	CABGA	I
	71V416S15BEI	BE48	CABGA	I
	71V416S15BEI8	BE48	CABGA	I
	71V416S15PHG	PHG44	TSOP	С
	71V416S15PHG8	PHG44	TSOP	С
	71V416S15PHGI	PHG44	TSOP	I
	71V416S15PHGI8	PHG44	TSOP	ı
	71V416S15YG	PBG44	SOJ	С
	71V416S15YG8	PBG44	SOJ	С
	71V416S15YGI	PBG44	SOJ	Ī
	71V416S15YGI8	PBG44	SOJ	Ţ

3624 tbl 12c

3624 tbl 12d

Datasheet Document History

08/05/99:		Updated to new format
	Pg 6	Revised footnote for tow on Write Cycle No. 1 diagram
08/31/99:	Pg. 1–9	Added Industrial temperature range offering
	Pg. 9	Added Datasheet Document History
03/24/00:	Pg. 6	Changed note to Write cycle No. 1 according to footnotes
08/10/00:		Add 48 ball grid array package offering
	Pg. 1	Correct TTL to LVTTL
09/11/ 02:	Pg. 2	Updated TBD information for the 48 BGA Capacitance table
11/26/02:	Pg. 8	Added "Die Revision" to ordering information
07/31/03:	Pg. 8	Updated note, L10 speed grade commercial temperature only and updated die stepping from YF to Y.
10/13/03:	Pg. 8	Updated ordering information. Refer to 71V416YS and 71V416YL datasheet for latest generation die
		step.
01/30/04:	Pg. 8	Added "Restricted hazardous substance device" to ordering information
02/01/13:	Pg. 1	Removed IDT reference to fabrication
	Pg. 8	Removed die revision information from the Ordering Information
11/18/16:	Pg. 2	Updated the orderable part numbers for all pin configurations
		Added the corrected configuration title for the 48 BGA pin configuration
		Reformatted SOJ/TSOP pins & labels. No change in functionality. It remains the same
	Pg.4	Updated the Industrial values and the footnote references in the DC Electrical table
	Pg. 5	Updated the footnote references in the AC Electrical table
	Pg. 8	Updated the orderable part numbers in the Ordering Information
	Pg. 8-9	Added orderable part information tables
05/26/21:	Pg. 1 - 10	Rebranded as Renesas datasheet
	Pg. 2 & 8	Updated package codes

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